





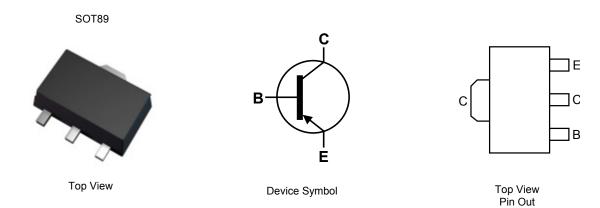
#### **60V PNP MEDIUM POWER TRANSISTOR IN SOT89**

#### **Features**

- BV<sub>CEO</sub> > -60V
- I<sub>C</sub> = -1A high Continuous Collector Current
- I<sub>CM</sub> = -2A Peak Collector Current
- R<sub>CE(SAT)</sub> = 295mΩ for a Low Equivalent On-Resistance
- h<sub>FE</sub> characterized up to 2A for high current gain hold up
- Complementary NPN type: FCX491
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.05 grams (Approximate)



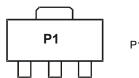
### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX591TA	P1	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



P1 = Product Type Marking Code



## **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I <sub>CM</sub>	-2	Α
Base Current	I <sub>B</sub>	-200	mA

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	P <sub>D</sub>	1.5	W	
	(Note 7)		2.0		
	(Note 5)		125	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{\theta JA}$	83		
	(Note 7)		60		
Thermal Resistance, Junction to Lead (Note 8)		R <sub>θJL</sub>	22		
Thermal Resistance, Junction to Case	(Note 9)	$R_{ heta JC}$	16		
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-65 to +150	°C		

## ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

- order still all conductors whist operating in a steady-state.

  Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

  Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.

  Thermal resistance from junction to solder-point (on the exposed collector pad).

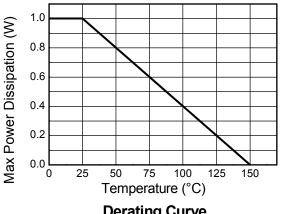
  Thermal resistance from junction to the top of the case.

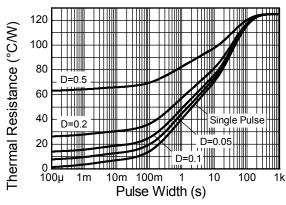
  Refer to JEDEC specification JESD22-A114 and JESD22-A115.





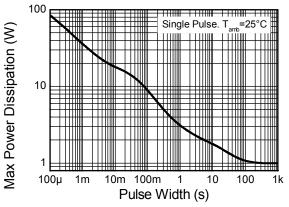
## **Thermal Characteristics and Derating Information**



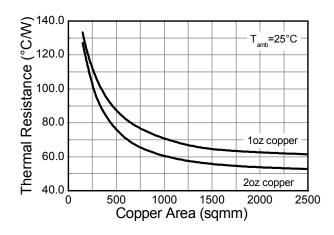


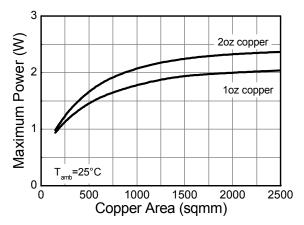
**Derating Curve** 

**Transient Thermal Impedance** 



## **Pulse Power Dissipation**









# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

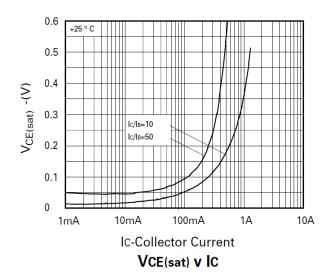
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-80	_	_	V	$I_C = -100\mu A$ , $I_E = 0$
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-60	_	_	V	$I_C = -10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.1	_	V	$I_E = -100\mu A$ , $I_C = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	<1	-100	nA	V <sub>CB</sub> = -60V
Emitter Cutoff Current	I <sub>EBO</sub>	_	<1	-100	nA	V <sub>EB</sub> = -5.6V, I <sub>C</sub> = 0
Emitter Cutoff Current	I <sub>CES</sub>	_	<1	-100	nA	V <sub>CES</sub> = -60V
DC current transfer Static ratio (Note 11)	h <sub>FE</sub>	100 100 80 15	220 175 155 40	— 300 —	_	$I_{C}$ = -1mA, $V_{CE}$ = -5V $I_{C}$ = -500mA, $V_{CE}$ = -5V $I_{C}$ = -1A, $V_{CE}$ = -5V $I_{C}$ = -2A, $V_{CE}$ = -5V
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	_	-155 -295	-300 -600	mV	$I_C = -500$ mA, $I_B = -50$ mA $I_C = -1$ A, $I_B = -100$ mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	_	-965	-1200	mV	$I_C = -1A$ , $I_B = -100$ mA
Base-Emitter Turn-on Voltage (Note 11)	V <sub>BE(on)</sub>	_	-830	-1000	mV	I <sub>C</sub> = -1A, V <sub>CE</sub> = -5V
Transitional Frequency	f <sub>T</sub>	150	_	_	MHz	I <sub>E</sub> = -50mA, V <sub>CE</sub> = -10V f = 100MHz
Output capacitance	C <sub>obo</sub>	_	_	10	pF	V <sub>CB</sub> = -10V, f = 1MHz,

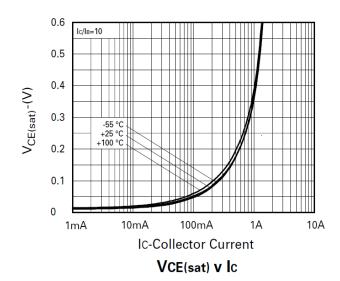
Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

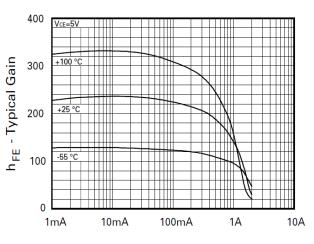


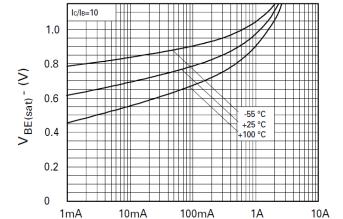


## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



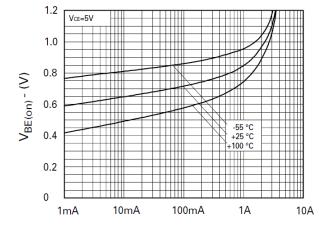






**Ic-Collector Current** hFE V IC

**Ic-Collector Current** VBE(sat) v Ic



**IC-Collector Current** VBE(on) v IC

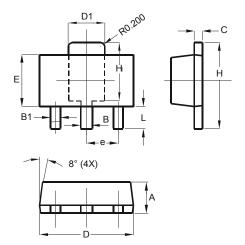
10A





# **Package Outline Dimensions**

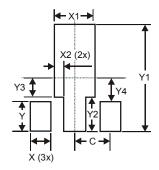
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
I	3.94	4.25		
H1	2.63 2.93			
L	0.89	1.20		
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1 500





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